

# PC924

## OPIC Photocoupler for IGBT Drive of Inverter

- ※ Lead forming type (I type) and taping reel type (P type) are also available. (PC924I/PC924P)
- ※ TÜV (VDE 0884) approved type is also available as an option.

### ■ Features

- Built-in direct drive circuit for IGBT drive  
( $I_{O1P}$ ,  $I_{O2P}$  : 0.4A)
- High speed response ( $t_{PLH}$ ,  $t_{PHL}$  : MAX. 2.0  $\mu$ s)
- Wide operating supply voltage range  
( $V_{CC}$  : 15 to 30V at  $T_a = -10$  to 60°C)
- High noise resistance type  
 $CM_H$  : MIN. -1 500V/ $\mu$ s  
 $CM_L$  : MIN. 1 500V/ $\mu$ s
- High isolation voltage ( $V_{iso}$  : 5 000V<sub>rms</sub>)

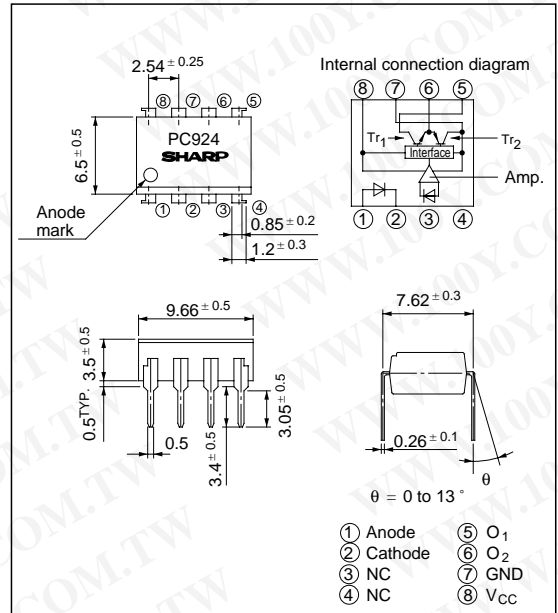
### ■ Applications

- IGBT drive for inverter control

勝特力材料 886-3-5753170  
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### ■ Outline Dimensions

(Unit : mm)



\* "OPIC" (Optical IC) is a trademark of the SHARP Corporation.  
 An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

### ■ Absolute Maximum Ratings

(Unless specified,  $T_a = T_{opr}$ )

	Parameter	Symbol	Rating	Unit
Input	Forward current	$I_F$	25	mA
	Reverse voltage	$V_R$	6	V
	Supply voltage	$V_{CC}$	35	V
Output	O <sub>1</sub> output current	$I_{O1}$	0.1	A
	*1 O <sub>1</sub> peak output current	$I_{O1P}$	0.4	A
	O <sub>2</sub> output current	$I_{O2}$	0.1	A
	*1 O <sub>2</sub> peak output current	$I_{O2P}$	0.4	A
	O <sub>1</sub> output voltage	$V_{O1}$	35	V
	Power dissipation	$P_O$	500	mW
	Total power dissipation	$P_{tot}$	550	mW
	*2 Isolation voltage	$V_{iso}$	5 000	V <sub>rms</sub>
Operating temperature	$T_{opr}$	- 25 to + 80	°C	
Storage temperature	$T_{stg}$	- 55 to + 125	°C	
*3 Soldering temperature	$T_{sol}$	260	°C	

\*1 Pulse width  $\leq$  0.15  $\mu$ s,  
 Duty ratio : 0.01  
 \*2 40 to 60% RH, AC for  
 1 minute,  $T_a = 25^\circ$ C  
 \*3 For 10 seconds

## ■ Electro-optical Characteristics

( $T_a = T_{opr}$  unless otherwise specified)

Parameter		Symbol	*4 Conditions	MIN.	TYP.	MAX.	Unit	Fig.			
Input	Forward voltage	$V_{F1}$	$T_a = 25^\circ\text{C}, I_F = 20\text{mA}$	-	1.2	1.4	V	-			
		$V_{F2}$	$T_a = 25^\circ\text{C}, I_F = 0.2\text{mA}$	0.6	0.9	-	V	-			
	Reverse current	$I_R$	$T_a = 25^\circ\text{C}, V_R = 4\text{V}$	-	-	10	$\mu\text{A}$	-			
	Terminal capacitance	$C_t$	$T_a = 25^\circ\text{C}, V = 0, f = 1\text{kHz}$	-	30	250	pF	-			
Output	Operating supply voltage	$V_{CC}$	$T_a = -10 \text{ to } 60^\circ\text{C}$	15	-	30	V	-			
				15	-	24	V	-			
	O <sub>1</sub> low level output voltage	$V_{O1L}$	$V_{CC1} = 12\text{V}, V_{CC2} = -12\text{V}$ $I_{O1} = 0.1\text{A}, I_F = 10\text{mA}$	-	0.2	0.4	V	1			
	O <sub>2</sub> high level output voltage	$V_{O2H}$	$V_{CC} = V_{O1} = 24\text{V}, I_{O2} = -0.1\text{A}, I_F = 10\text{mA}$	18	21	-	V	2			
	O <sub>2</sub> low level output voltage	$V_{O2L}$	$V_{CC} = 24\text{V}, I_{O2} = 0.1\text{A}, I_F = 0$	-	1.2	2.0	V	3			
	O <sub>1</sub> leak current	$I_{O1L}$	$T_a = 25^\circ\text{C}, V_{CC} = V_{O1} = 35\text{V}, I_F = 0$	-	-	500	$\mu\text{A}$	4			
	O <sub>2</sub> leak current	$I_{O2L}$	$T_a = 25^\circ\text{C}, V_{CC} = V_{O2} = 35\text{V}, I_F = 10\text{mA}$	-	-	500	$\mu\text{A}$	5			
	High level supply current	$I_{CCH}$	$T_a = 25^\circ\text{C}, V_{CC} = 24\text{V}, I_F = 10\text{mA}$	-	6	10	mA	6			
			$V_{CC} = 24\text{V}, I_F = 10\text{mA}$	-	-	14	mA				
Low level supply current	$I_{CCL}$	$T_a = 25^\circ\text{C}, V_{CC} = 24\text{V}, I_F = 0$	-	8	13	mA	6				
		$V_{CC} = 24\text{V}, I_F = 0$	-	-	17	mA					
Transfer characteristics	*5 “Low→High” threshold input current	$I_{FLH}$	$T_a = 25^\circ\text{C}, V_{CC} = 24\text{V}$	1.0	4.0	7.0	mA	7			
			$V_{CC} = 24\text{V}$	0.6	-	10.0	mA				
	Response time	Isolation resistance	$R_{ISO}$	$T_a = 25^\circ\text{C}, \text{DC} = 500\text{V}, 40 \text{ to } 60\% \text{RH}$	$5 \times 10^{10}$	$10^{11}$	-	$\Omega$	-		
				“Low→High” propagation delay time	$t_{PLH}$	-	1.0	2.0	$\mu\text{s}$	8	
				“High→Low” propagation delay time	$t_{PHL}$	$T_a = 25^\circ\text{C}, V_{CC} = 24\text{V}, I_F = 10\text{mA}$	-	1.0	2.0		$\mu\text{s}$
				Rise time	$t_r$	$R_C = 47\Omega, C_G = 3,000\text{pF}$	-	0.2	0.5		$\mu\text{s}$
	Fall time	$t_f$		-	0.2	0.5	$\mu\text{s}$				
Instantaneous common mode rejection voltage “Output: High level”	$CM_H$	$T_a = 25^\circ\text{C}, V_{CM} = 600\text{V(peak)}$ $I_F = 10\text{mA}, V_{CC} = 24\text{V}, \Delta V_{O2H} = 2.0\text{V}$	-	-30	-	kV/ $\mu\text{s}$	9				
		Instantaneous common mode rejection voltage “Output: Low level”	$CM_L$	$T_a = 25^\circ\text{C}, V_{CM} = 600\text{V(peak)}$ $I_F = 0, V_{CC} = 24\text{V}, \Delta V_{O2L} = 2.0\text{V}$	-	30		-	kV/ $\mu\text{s}$		

\*4 When measuring output and transfer characteristics, connect a by-pass capacitor ( 0.01  $\mu\text{F}$  or more ) between  $V_{CC}$  and GND near the device.

\*5  $I_{FLH}$  represents forward current when output goes from “Low” to “High” .

## ■ Truth Table

Input	O <sub>2</sub> Output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

■ Test Circuit

Fig. 1

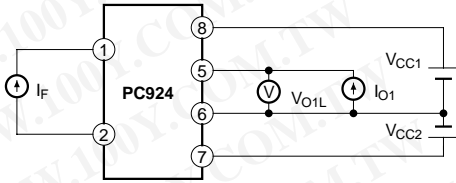


Fig. 2

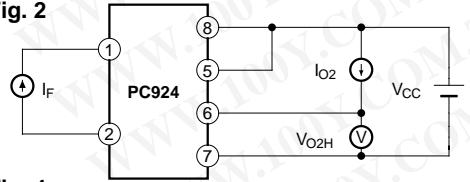


Fig. 3

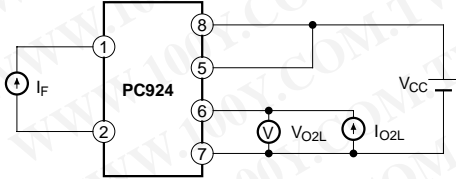


Fig. 4

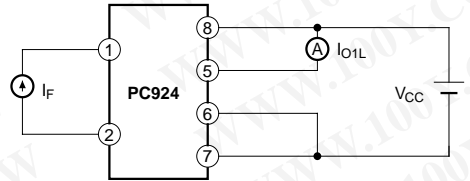


Fig. 5

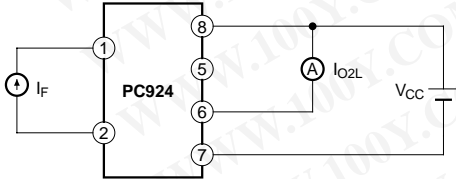


Fig. 6

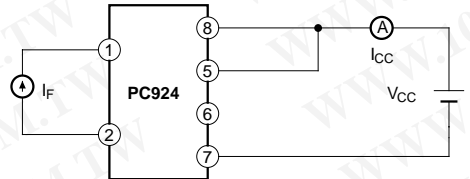


Fig. 7

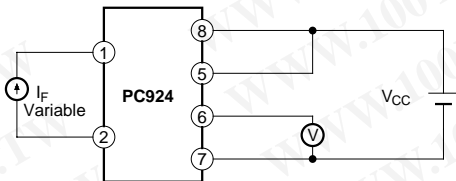


Fig. 8

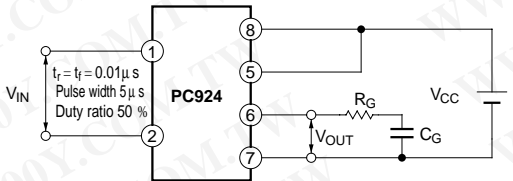
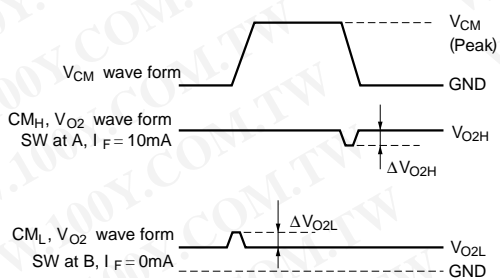
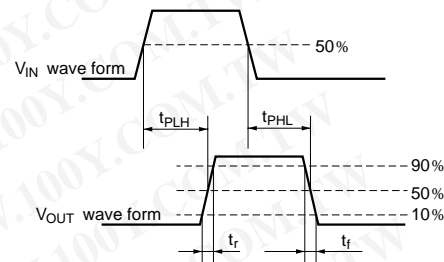
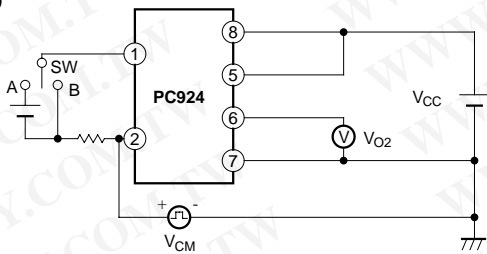
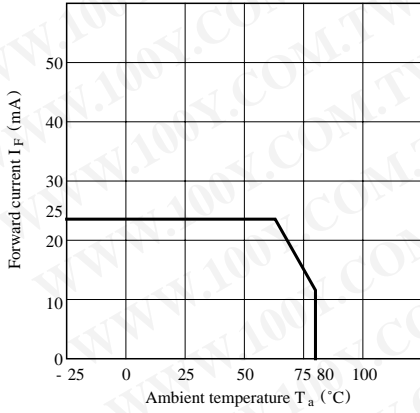


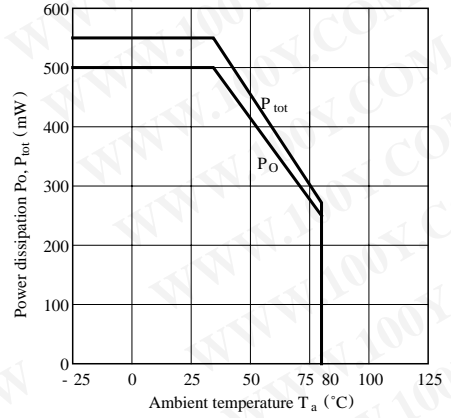
Fig. 9



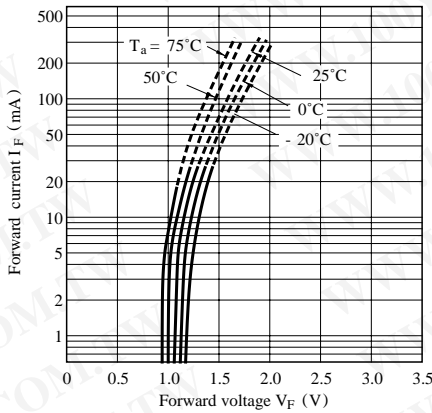
**Fig.10 Forward Current vs. Ambient Temperature**



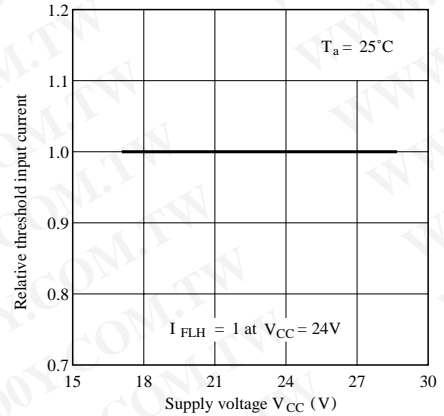
**Fig.11 Power Dissipation vs. Ambient Temperature**



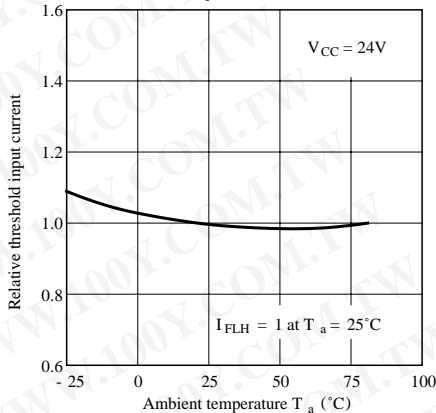
**Fig.12 Forward Current vs. Forward Voltage**



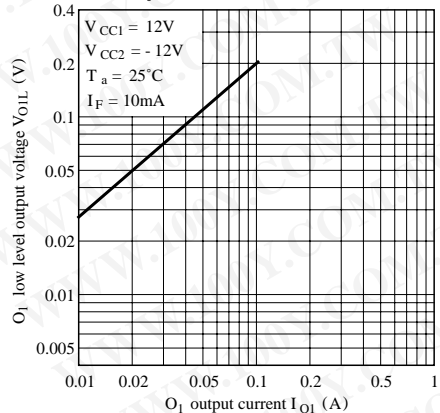
**Fig.13 Relative Threshold Input Current vs. Supply Voltage**



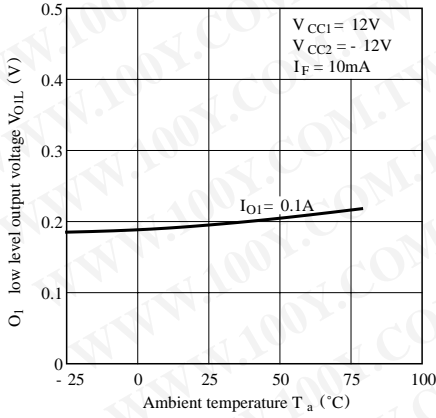
**Fig.14 Relative Threshold Input Current vs. Ambient Temperature**



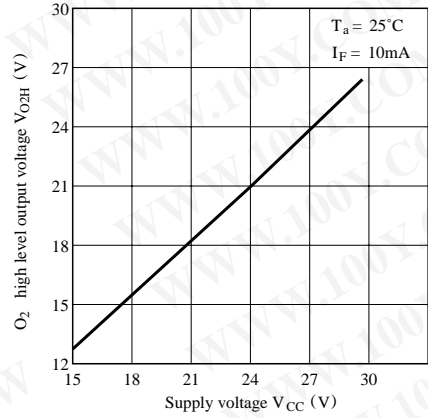
**Fig.15 O<sub>1</sub> Low Level Output Voltage vs. O<sub>1</sub> Output Current**



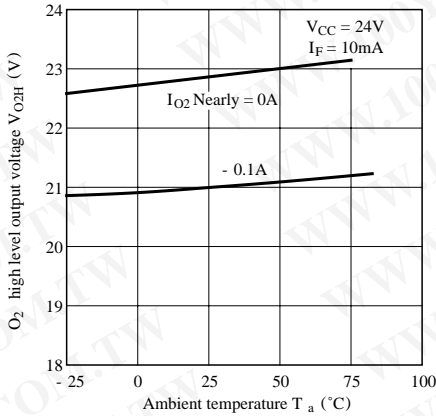
**Fig.16 O<sub>1</sub> Low Level Output Voltage vs. Ambient Temperature**



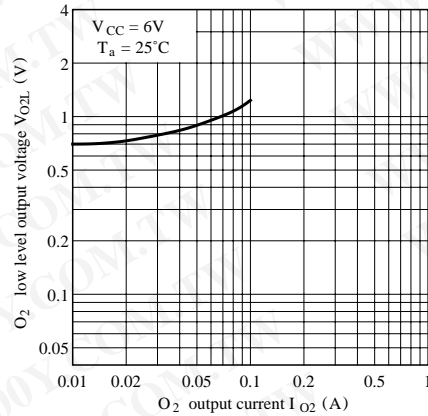
**Fig.17 O<sub>2</sub> High Level Output Voltage vs. Supply Voltage**



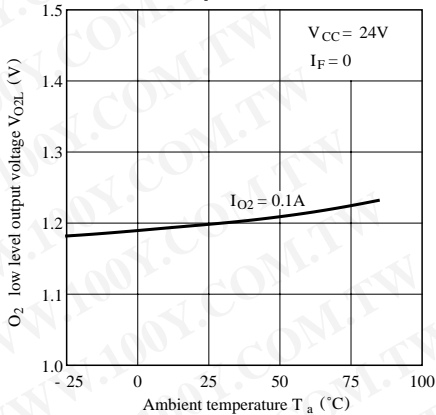
**Fig.18 O<sub>2</sub> High Level Output Voltage vs. Ambient Temperature**



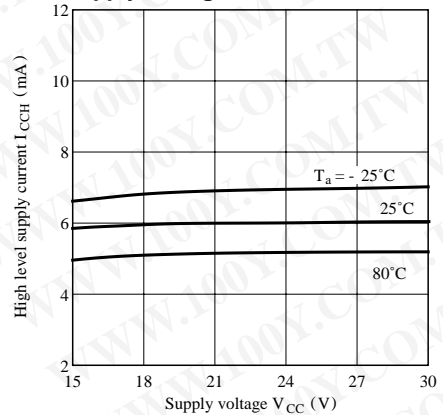
**Fig.19 O<sub>2</sub> Low Level Output Voltage vs. O<sub>2</sub> Output Current**



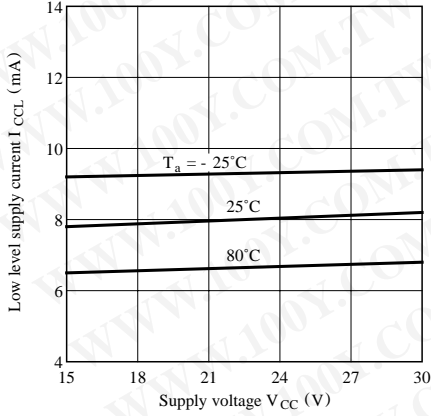
**Fig.20 O<sub>2</sub> Low Level Output Voltage vs. Ambient Temperature**



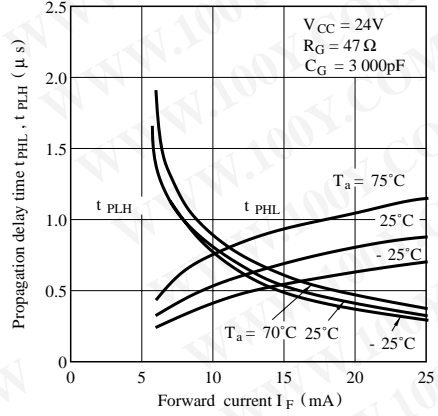
**Fig.21 High Level Supply Current vs. Supply Voltage**



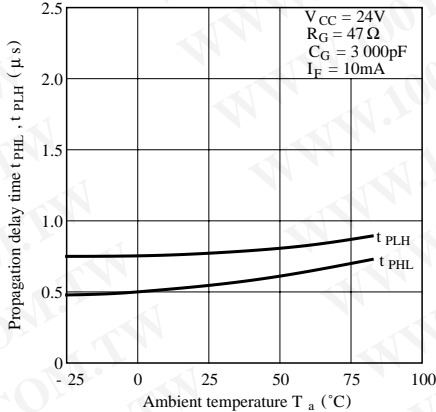
**Fig.22 Low Level Supply Current vs. Supply Voltage**



**Fig.23 Propagation Delay Time vs. Forward Current**

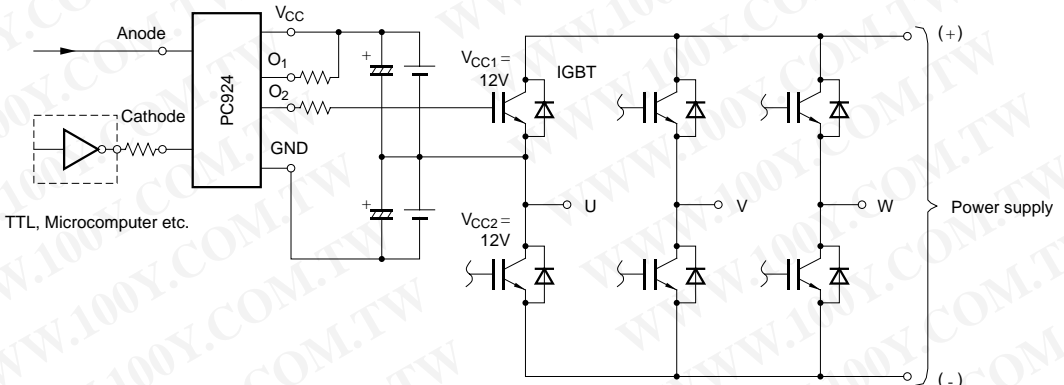


**Fig.24 Propagation Delay Time vs. Ambient Temperature**



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■ Application Circuit (IGBT Drive for Inverter)



● Please refer to the chapter “Precautions for Use”